

Silicon carbide power schottky diode

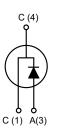




D-PAK

Features

- Rated to 1200V at 5 Amps
- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behaviour
- High temperature operation
- High frequency operation
- Marking code : ESIC05120SD



RoHS Pb

Application

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS,
- Wind turbine, Rail traction, EV/HEV

Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- $\boldsymbol{\cdot}$ No thermal run-away with parallel devices
- Reduced heat sink requirements

Ordering	Information	

Part No.	Remark	Package	Packing
ESIC05120SD	RoHS Compliant	D-PAK	2500 / Tape & Reel
ESIC05120SD-H	Halogen Free	D-FAR	2000 / Tape & Reel

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Conditions	Symbol	Limits	Unit
Repetitive Peak Reverse Voltage	T _j =25°C	V _{RRM}	1200	V
Surge Peak Reverse Voltage	T _j =25°C	V _{RSM}	1200	V
DC Blocking Voltage	T _j =25°C	V _{DC}	1200	V
Continuous Forward Current	Tj=25°C Tj=135°C Tj=158°C	IF	18 8.5 5	A
Repetitive Peak Forward Surge Current	T _C =25°C , tp=10ms, Half Sine Wave, D=0.3	I _{FRM}	25	А
Non-Repetitive Peak Forward Surge Current	T _C =25°C , tp=10ms, Half Sine Wave	I _{FSM}	50	А
Power Dissipation	T _C =25°C	P _{TOT}	109.5	W
	T _c =110°C	' TOT	47	W
Operating Junction and Storage Temperature		Tj ∖ Tstg	-55~+175	°C
Typical Thermal Resistance form Junction to Case		R _{eJC}	1.37	°C/ W



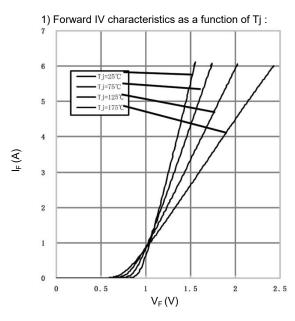
Silicon carbide power schottky diode

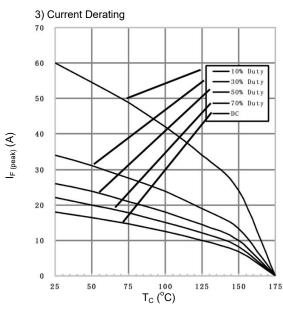
RoHS Pb

Electrical Characteristics (T_A = 25 °C unless otherwise specified)

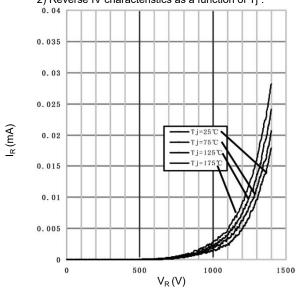
Parameter	Conditions	Symbol	Min.	Тур.	Max.	Unit
Forward Voltage	I _F =5A, T _j =25°C	V _F	-	1.45	1.7	V
Forward Voltage	I _F =5A, T _j =175°C	۷F	-	2.05	2.5	v
Reverse Current	V _R =1200V, T _j =25°C	I	-	20	100	μA
	V _R =1200V, T _j =175°C	I _R	-	50	200	μΛ
Total Capacitive Charge	$V_{R}=800V, T_{j}=150^{\circ}C$ $Qc = \int_{0}^{VR} C(V) dV$	Q _C	-	36	-	nC
	V _R =0V, T _j =25°C, f=1MHZ		-	475	510	
Total Capacitance	V _R =400V, T _j =25°C, f=1MHZ	С	-	34	44	pF
	V _R =800V, T _j =25°C, f=1MHZ		-	33	40	

Rating and Characteristics Curves

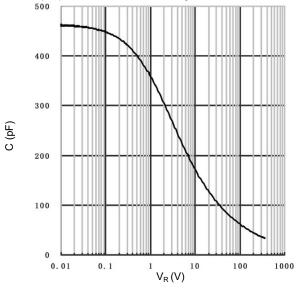




2) Reverse IV characteristics as a function of Tj :



4)Capacitance vs. reverse voltage :

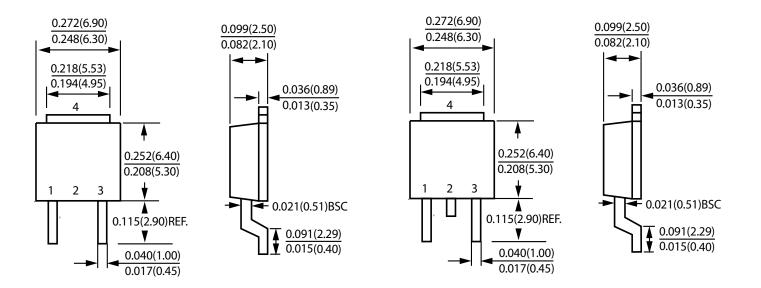




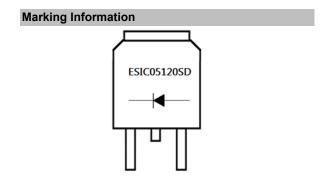
Silicon carbide power schottky diode

RoHS Pb

Package Outline Dimensions

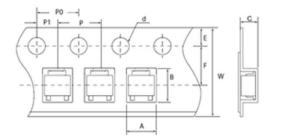


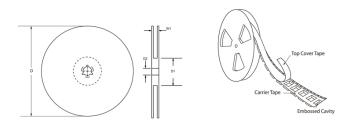
D-PAK Dimensions in inches and (millimeters)



Tape & Reel Specification				
Item	Symbol	D-PAK		
Item	Symbol	(mm)		
Carrier width	А	6.93 ± 0.13		
Carrier length	В	10.5±0.10		
Carrier depth	С	2.72 ± 0.17		
Sprocket hole	d	1.55 ± 0.10		
Reel outside diameter	D	330 ± 2.0		
Feed hole diameter	D0	13 (min)		
Reel inner diameter	D1	90 (min)		
Sprocket hole position	E	1.75 ± 0.10		
Punch hole position	F	7.50 ± 0.10		
Sprocket hole pitch	Р	8.00 ± 0.10		
Sprocket hole pitch	P0	4.00 ± 0.2		
Embossment center	P1	2.00 ± 0.10		
Tape width	W	16.00 ± 0.3		
Reel width	W1	16.30 ± 0.9		

Suggested Pad Layout				
Outline	D-PAK			
Symbol	(mm)			
A	3.00	≪ B→		
В	3.70			
С	6.00			
D	6.50	Ĭ		
E	4.60	→		
F	1.40			





RoHS Pb



Silicon carbide power schottky diode

LEGAL DISCLAIMER

- The product is provided "AS IS" without any guarantees or warranty. In association with the product, Eris Technology Corporation, its affiliates, and their directors, officers, employees, agents, successors and assigns (collectively, the "Eris") makes no warranties of any kind, either express or implied, including but not limited to warranties of merchantability, fitness for a particular purpose, of title, or of non-infringement of third party rights.
- The information in this document and any product described herein are subject to change without notice and should not be construed as a commitment by Eris. Eris assumes no responsibility for any errors that may appear in this document.
- Eris does not assume any liability arising out of the application or use of this document or any product described herein, any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Eris and all the companies whose products are represented on Eris website, harmless against all damages.
- No license, express or implied, by estoppels or otherwise, to any intellectual property is granted by this document or by any conduct of Eris. Product name and markings notes herein may be trademarks of their respective owners.
- Eris does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- Should Customers purchase or use Eris products for any unintended or unauthorized application, Customers shall indemnify and hold Eris and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.
- The official text is written in English and the English version of this document is the only version endorsed by Eris. Any discrepancies or differences created in the translations are not binding and have no legal effect on Eris for compliance or enforcement purposes.